

LI-ION/POLYMER ONE CELL PROTECTOR

DESCRIPTION

The EUP9261 series are lithium-ion/lithium polymer rechargeable battery protection ICs incorporating high-accuracy voltage detection circuit and delay circuit. The EUP9261 series are suitable for protection of single-cell lithium-ion/lithium polymer battery packs from overcharge, overdischarge and overcurrent.

FEATURES

• Absolute maximum rating of 30V for the charger connection pins(VM and CO)

Highly accurate voltage detector	Overcharge detection (1	opt=+25°C)	±25mV
	(`	Fopt=-5 to 55°C)	±30mV
www.DataSheet4U.com	Overcharge hysteresis		±25mV
	Overdischarge detection	1	±50mV
	Overcurrent 1 detection		±15mV
	Overcurrent 2 detection	±	100mV
Variety of detector	Overcharge detection	3.9V-4.4V step	of 5mV
	Overcharge hysteresis	0.0V-0.4V ^{*1} step o	of 50mV
	Overdischarge detection	2.0V-3.0V step o	of 10mV
	Overdischarge hysteres	s 0.0V-0.7V ^{*2} step of	100mV
	Overcurrent 1 detection	0.03V-0.3V step	of 10mV
	Overcurrent 2 detection		0.5V

*1 Overcharge release voltage=Over detection voltage-Overcharge hysteresis voltage *2 Overdischarge release voltage = Overdischarge detection voltage-Overdischarge hysteresis voltage.

- Delay times internally generated. Accuracy : ±30%.
 (overcharge: t_{CU}, overdischarge: t_{DL}, overcurrent 1: t_{IOV1}, overcurrent 2: t_{IOV2})
- Three-step overcurrent detection circuit is included.(overcurrent 1,overcurrent 2 and load short circuiting)
- Charger detection function and abnormal charge current detection function, included.
- 0V-battery charge option: Acceptable/Unacceptable.
- Low current consumption
 - Operation: 3.0µA typ. 6µA max.
 - Power-down 0.1µA max.
- DP pin.....At V_{SS} level, delay circuit is disabled. Tie a 300kΩ resistor to V_{SS}, delay time of all items expect short-circuit can be reduced.
- Wide operating temperature range: -40°C to + 85°C.
- Small package: SOT-23-6, STDFN-6(2mm*2mm)
- RoHS compliant and 100% lead (Pb)-free

APPLICATIONS

- Lithium-ion rechargeable battery packs.
- Lithium polymer rechargeable battery packs.



Block Diagram

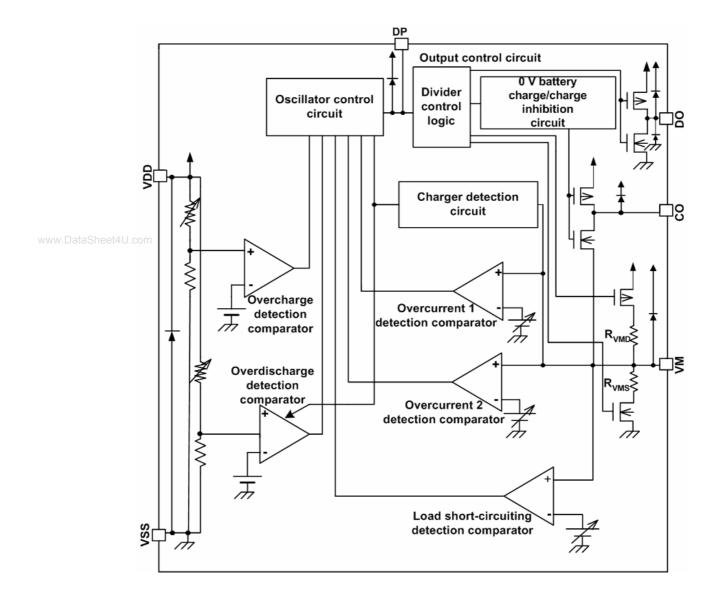
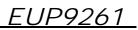


Figure1.



Pin Configurations

Package Type	Pin Configurations				
SOT-23-6	$V_{SS} V_{DD} DP$ $6 5 4$ $1 2 3$ $DO VM CO$				
STDFN-6 w.DataSheet4U.com	$ \begin{array}{c} CO & 1 \\ VM & 2 \\ V_{DD} \\ V_{DD} \\ S \\ V_{DD} \\ V_{DD} \\ V_{DD} \\ V_{SS} \\ $				

Pin Description

PIN	SOT-23-6	STDFN6	DESCRIPTION
DO	1	3	DO FET gate control pin for discharge (CMOS output)
\/N/I			VM Voltage detection pin between VM and VSS
VM 2		2	(Overcurrent detection pin)
СО	3	1	CO FET gate control pin for charge(CMOS output)
DP	4	6	Pin for reduce output delay time and for delay time measurement
V _{DD}	5	5	V _{DD} Positive power input pin
V _{SS}	6	4	V _{SS} Negative power input pin

Absolute Maximum Ratings

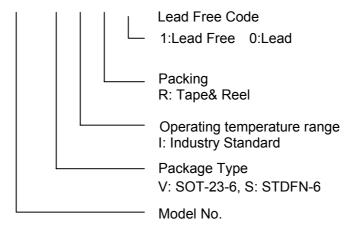
•	Input voltage between V_{DD} and V_{SS}	V _{SS} -0.3 V to	V _{SS} +12 V
•	Input pin voltage for VM	V_{DD} -30 V to V	/ _{DD} +0.3 V
•	Output pin voltage for CO	V_{VM} -0.3 V to V	/ _{DD} +0.3 V
	Output pin voltage for DO	$V_{\rm SS}$ -0.3 V to V	/ _{DD} +0.3 V
•	Power dissipation SOT-23-6		250mW
•	Operating temperature range	40°0	C to +85°C
	Storage temperature range	55°C	to +125°C
•	ESD Susceptibility		
	HBM (Human Body Mode)		>1KV
	MM (Machine Mode)		>200V

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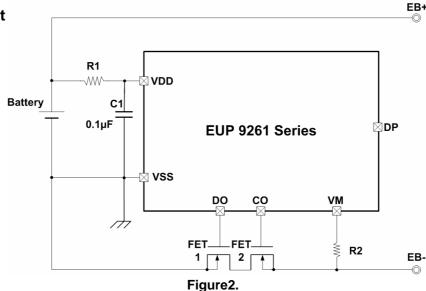
Ordering Information

	Order Number	Package Type	Marking	Operating Temperature range
	EUP9261AJVIR1	SOT-23-6	BJ	-40°C to 85°C
	EUP9261AJVIR0	SOT-23-6	BJ	-40°C to 85°C
	EUP9261BJVIR1	SOT-23-6	BT	-40°C to 85°C
	EUP9261BJVIR0	SOT-23-6	BT	-40°C to 85°C
	EUP9261BOVIR1	SOT-23-6	BO	-40°C to 85°C
	EUP9261BOVIR0	SOT-23-6	BO	-40°C to 85°C
	EUP9261BQVIR1	SOT-23-6	BQ	-40°C to 85°C
	EUP9261BQVIR0	SOT-23-6	BQ	-40°C to 85°C
	EUP9261BPVIR1	SOT-23-6	BP	-40°C to 85°C
.DataS	EUP9261BPVIR0	SOT-23-6	BP	-40°C to 85°C
	EUP9261BBVIR1	SOT-23-6	BB	-40°C to 85°C
	EUP9261BBVIR0	SOT-23-6	BB	-40°C to 85°C
	EUP9261BFVIR1	SOT-23-6	BF	-40°C to 85°C
	EUP9261BFVIR0	SOT-23-6	BF	-40°C to 85°C
	EUP9261BJSIR1	STDFN-6	ВТ	-40°C to 85°C

EUP9261



Application Circuit



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Symbol	Parts	Purpose	Recommend	min.	max.	Remarks
FET1	N channel	Charge control				Threshold voltage ≤ Overdischarge detection voltage *1
	MOSFET	Charge control				Gate to source withstand voltage ≥ Charge voltage*2
FET2	N channel	Discharge control				Threshold voltage ≤ Overdischarge detection voltage *1
1 [1 2	MOSFET	Discharge control				Gate to source withstand voltage ≥ Charge voltage*2
R1	Resistor	ESD protection For power fluctuation	470Ω	300Ω	1kΩ	Resistance should be as small as possible to avoid lowering of the overcharge detection accuracy caused by VDD pin current. *3
C1	Capacitor	For power fluctuation	0.1µF	0.022µF	1.0µF	Install a capacitor of 0.022µF or higher between VDD and VSS. *4
R2	Resistor	Protection for reverse connection of a charger	2kΩ	300Ω	4kΩ	Select a resistance as large as possible to prevent current when a charger is reversely connected. *5

*1 If the threshold voltage of an EFT is low, the FET may not cut the charging current.

If an FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stoped before overdischarge is detected.

- *2 If the withstand voltage between the gate and source is lower than the charger voltage, the FET may destroy.
- *3 If R1 has a high resistance, the voltage between VDD and VSS may exceed the absolute maximum rating when a charger is connected reversely since the current flows from the charger to the IC.

Insert a resistor of 300Ω or higher as R1 for ESD protection.

*4 If a capacitor of less than 0.022µF is installed as C1,DO may oscillate when load short-circuiting is detected.

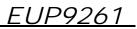
Be sure to install a capacitor of 0.022μ F or higher as C1.

*5 If R2 has a resistance higher than 4kΩ, the charging current may not be cut when a high-voltage charger is connected.

Remark The DP pin should be open.

Caution The above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.





Product name list

Model No.	Overcharge detection voltage[V _{cu}]	Overcharge Hysteresis voltage[V _{HC}]	Overdischarge detection voltage [V _{DL}]	Overdischarge hysteresis voltage [V _{HD}]	Overcurrent 1 detection voltage [V _{IOV1}]	0V battery charge function
EUP9261AJ	4.325 V	0.25V	2.5V	0.4V	0.150V	Unavailable
EUP9261BJ	4.28	0.2V	3.0V	0V	0.080V	Available
EUP9261BO	4.28	0.2V	2.3V	0V	0.040V	Available
EUP9261BQ	4.28	0.2V	2.9V	0.1V	0.030V	Available
EUP9261BP	4.35	0.2V	2.3V	0.7V	0.200V	Available
EUP9261BB	4.28	0.3V	2.3V	0.1V	0.125V	Available
EUP9261BF	4.28	0.2V	2.8V	0V	0.050V	Available

Model No.	Overcharge detection delay time	Overdischarge detection delay time	Overcurrent 1 detection delay time		
www.DataShEUP9261AJ	1.3s	175ms	12ms		
EUP9261BJ	1.3s	175ms	12ms		
EUP9261BO	1.3s	175ms	12ms		
EUP9261BQ	1.3s	175ms	12ms		
EUP9261BF	1.3s	175ms	12ms		
EUP9261BP	144ms	40ms	20ms		
EUP9261BB	144ms	40ms	20ms		

Note: It is possible to change the detection voltages of the product other than above. The delay times can also be changed within the range listed bellow. For details, please contact our sales office.

<u>EUP9261</u>

Electrical Characteristics (1) Except detection delay time (25°C)

Symbol	Parameter	Remark	Min	Тур	Max	Unit	Measurement circuit
Detectio	n Voltage						Circuit
	Overcharge detection voltage		V _{CU} -0.025	V _{CU}	V _{CU} +0.025	V	1
V _{CU}	V_{CU} = 3.9 V to 4.4 V, 5 mV Step	Ta = -5° C to 55° C ^{*1}	V _{CU} -0.030	V _{CU}	V _{CU} +0.030	V	I
V_{HC}	Overcharge hysteresis voltage V _{HC} =0.0V to 0.4V, 50mV Step		V _{HC} -0.025	V_{HC}	V _{HC} +0.025	V	1
V_{DL}	Overdischarge detection voltage V_{DL} =2.0 V to 3.0 V, 10 mV Step		V _{DL} -0.050	V _{DL}	V _{DL} +0.050	V	2
V_{HD}	Overdischarge hysteresis voltage V_{HD} =0.0V to 0.7V, 100mV Step		V _{HD} -0.050	V_{HD}	V _{HD} +0.050	V	2
V_{IOV1}	Overcurrent 1 detection voltage V _{IOV1} =0.05V to 0.3V,10mV Step		V _{IOV1} -0.015	V _{IOV1}	V _{IOV1} +0.015	V	2
wwViotaSh	Overcurrent 2 detection voltage		0.4	0.5	0.6	V	2
V _{SHORT}	Load short-circuiting detection voltage		0.7	1	1.3	V	2
V _{CHA}	Charge detection voltage		-1.3	-1.0	-0.7	V	2
Input Vo	Itage, Operation Voltage						
V_{DSOP1}	Operation voltage between V_{DD} and V_{SS}	Internal circuit operating voltage	1.5		8	V	
V_{DSOP2}	Operation voltage between $V_{\mbox{\scriptsize DD}}$ and $V_{\mbox{\scriptsize M}}$	Internal circuit operating voltage	1.5		28	V	
Current	Consumption			-			
I _{OPE}	Current consumption in normal operation	V_{DD} =3.5 V, V_{VM} =0 V	1.0	3.0	6.0	μA	2
I _{PDN}	Current consumption at power down	V _{DD} =V _{VM} =1.5 V			0.1	μA	2
Output I	Resistance			l		1	
R _{COH}	CO pin H resistance	V _{CO} =3.0V,V _{DD} =3.5V V _{VM} =0 V	2.5	5	10	kΩ	4
R _{COL}	CO pin L resistance	V _{CO} =0.5 V, V _{DD} = 4.5V, V _{VM} =0 V	2.5	5	10	kΩ	4
R_{DOH}	DO pin H resistance	V _{DO} =3.0 V, V _{DD} =3.5V, V _{VM} =0 V	2.5	5	10	kΩ	4
	DO pin L resistance	V _{DO} =0.5V V _{DD} =V _{VM} =1.8 V	2.5	5	10	kΩ	4
VM Inter	nal Resistance	1					
R_{VMD}	Internal resistance between VM and VDD	V_{DD} =1.8 V, V_{VM} =0 V	100	300	900	kΩ	3
R_{VMS}	Internal resistance between VM and VSS	V_{DD} =3.5 V, V_{VM} =1.0 V	15	35	60	kΩ	3
0V batte	ry charging function						
	0V battery charge starting charger voltage	0V battery charging available	1.2			V	2
V _{0INH}	0V battery charge inhibition battery voltage	0V battery charging unavailable			0.5	V	2

*1. Since products are not screened at low and high temperature, the specification for this temperature range is guaranteed by design not tested in production.

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Electrical Characteristics (2) Except detection delay time (-40°C to +85°C*¹)

(Ta= -40°C to +85°C*1 unless otherwise specified)

		(rwise specified)			
Symbol	Parameter	Remark	Min	Тур	Max	Unit	Measurement circuit
Detectio	on Voltage	•					
V_{CU}	Overcharge detection voltage VCU=3.9 V to 4.4 V, 5 mV Step		V _{CU} -0.055	V _{CU}	V _{CU} +0.040	V	1
V_{HC}	Overcharge hysteresis voltage V _{HC} =0.0V to 0.4V, 50mV Step		V _{HC} -0.030	V _{HC}	V _{HC} +0.030	V	1
V_{DL}	Overdischarge detection voltage V_{DL} =2.0 V to 3.0 V, 10 mV Step		V _{DL} -0.080	V _{DL}	V _{DL} +0.080	V	2
V_{HD}	Overdischarge hysteresis voltage V _{HD} =0.0V to 0.7V, 100mV Step		V _{HD} -0.050	V_{HD}	V _{HD} +0.050	V	2
V _{IOV1}	Overcurrent 1 detection voltage V _{IOV1} =0.05V to 0.3V,10mV Step		V _{IOV1} -0.025	V _{IOV1}	V _{IOV1} +0.025	V	2
V _{IOV2}	Overcurrent 2 detection voltage		0.37	0.5	0.63	V	2
V _{SHORT}	Load short-circuiting detection voltage		0.5	1	1.5	V	2
V _{CHA}	Charge detection voltage		-1.5	-1.0	-0.5	V	2
	ltage, Operation Voltage			1	1	1	
V _{DSOP1}	Operation voltage between V_{DD} and V_{SS}	Internal circuit operating voltage	1.5		8	V	
V_{DSOP2}	Operation voltage between $V_{\mbox{\scriptsize DD}}$ and $V_{\mbox{\scriptsize M}}$	Internal circuit operating voltage	1.5		28	V	
Current	Consumption	1	r	T	1	1	
I _{OPE}	Current consumption in normal operation	V_{DD} =3.5 V, V_{VM} = 0 V	0.7	3.0	8.0	μA	2
I _{PDN}	Current consumption at power down	V _{DD} =V, V _{VM} =1.5 V			0.1	μA	2
Output I	Resistance			1		1	
R _{COH}	CO pin H resistance	V _{CO} = 3.0 V, V _{DD} =3.5V, V _{VM} = 0 V	1.2	5	15	kΩ	4
R _{COL}	CO pin L resistance	V_{CO} =0.5 V, V_{DD} =4.5V, V_{VM} = 0 V	1.2	5	15	kΩ	4
R _{DOH}	DO pin H resistance	V_{DO} =3.0 V, V_{DD} =3.5V, V_{VM} = 0 V	1.2	5	15	kΩ	4
R _{DOL}	DO pin L resistance	V _{DO} =0.5V, V _{DD} =V _{VM} = 1.8V	1.2	5	15	kΩ	4
VM inter	rnal resistance		•			•	•
R_{VMD}	Internal resistance between V_{M} and V_{DD}	V _{DD} =1.8 V, V _{VM} =0 V	78	300	1310	kΩ	3
R _{VMS}	Internal resistance between V_{M} and V_{SS}	V _{DD} =3.5 V, V _{VM} =1.0 V	10	35	70	kΩ	3
0V batte	ery charging function	<u> </u>	1	1	I	1	I
V _{0CHA}	0V battery charge starting charger voltage	0V battery charging available	1.7			V	2
V _{0INH}	0V battery charge inhibition battery voltage	0V battery charging unavailable			0.3	V	2

*1.Since products are not screened at low and high temperature, the specification for this temperature range is guaranteed by design, no tested in production.



Electrical Characteristics (3) Detection delay time (I) EUP9261 AJ, EUP9261BJ, EUP9261BO, EUP9261BQ, EUP9261BF

Symbol	Parameter	Remark	Min.	Тур.	Max.	Unit	Measurement circuit
Delay tin	ne (25°C)				•		•
t _{cu}	Overcharge detection delay time		0.91	1.3	1.69	S	5
t _{DL}	Overdischarge detection delay time		122	175	228	ms	5
t _{IOV1}	Overcurrent 1 detection delay time		8.4	12	15.6	ms	5
t _{IOV2}	Overcurrent 2 detection delay time		2.1	3	3.9	ms	5
t _{short}	Load short-circuiting detection delay time		200	320	500	μs	5
Delay tin	ne (-40°C to +85°C) * ¹				•		
t _{CU}	Overcharge detection delay time		0.72	1.3	2.16	S	5
t _{DL}	Overdischarge detection delay time		97	175	291	ms	5
t _{IOV1}	Overcurrent 1 detection delay time		6.7	12	20	ms	5
t _{IOV2}	Overcurrent 2 detection delay time		1.5	3	5	ms	5
ww.DataSh t _{SHORT}	Load short-circuiting detection delay time		150	320	600	μs	5

(II) EUP9261BB, EUP9261BP

Symbol	Parameter	Remark	Min.	Тур.	Max.	Unit	Measurement circuit				
Delay tin	Delay time (25°C)										
t _{cu}	Overcharge detection delay time		100	144	187	ms	5				
t _{DL}	Overdischarge detection delay time		28	40	52	ms	5				
t _{IOV1}	Overcurrent 1 detection delay time		14	20	26	ms	5				
t _{IOV2}	Overcurrent 2 detection delay time		2.1	3	3.9	ms	5				
t _{short}	Load short-circuiting detection delay time		200	320	500	μs	5				
Delay tin	ne (-40°C to +85°C) * ¹										
t _{cu}	Overcharge detection delay time		80	144	240	ms	5				
t _{DL}	Overdischarge detection delay time		22.2	40	66.6	ms	5				
t _{IOV1}	Overcurrent 1 detection delay time		11	20	33	ms	5				
t _{IOV2}	Overcurrent 2 detection delay time		1.5	3	5	ms	5				
t _{short}	Load short-circuiting detection delay time		150	320	600	μs	5				



Measurement Circuits

Unless otherwise specified, the output voltage levels "H" and "L" at CO and DO pins are judged by the threshold voltage (1.0 V) of the N channel FET. Judge the CO pin level with respect to V_{VM} and the DO pin level with respect to V_{SS} .

(1) Measurement Condition 1, Measurement Circuit 1

Overcharge detection voltage, Overcharge hysteresis voltage.>

The overcharge detection voltage (V_{CU}) is defined by the voltage between VDD and VSS at which V_{CO} goes "L" from "H" when the voltage V1 is gradually increased from the starting condition V1=3.5V. The overcharge hysteresis voltage (V_{HC}) is then defined by the difference between the overcharge detection voltage (V_{CU}) and the voltage between VDD and VSS at which V_{CO} goes "H" www.from "L" when the voltage V1 is gradually decreased.

(2) Measurement Condition 2, Measurement Circuit 2

<Overdischarge detection voltage, Overdischarge hysteresis voltage >

The overdischarge detection voltage (V_{DL}) is defined by the voltage between VDD and VSS at which V_{DO} goes "L" from "H" when the voltage V1 is gradually decreased from the starting condition V1=3.5V and V2 =0V. The overdischarge hysteresis voltage (V_{HD}) is then defined by the difference between the overdischarge detection voltage (V_{DL}) and the voltage between VDD and VSS at which V_{DO} goes "H" from "L" when the voltage V1 is gradually increased.

(3) Measurement Condition 3, Measurement Circuit 2

<Overcurrent 1 detection voltage, Overcurrent 2 detection voltage, Load short-circuiting detection voltage.>

The overcurrent 1 detection voltage (V_{IOV1}) is defined by the voltage between VM and VSS at which V_{DO} goes "L" from "H" when the voltage V2 is gradually increased from the normal condition V1 =3.5V and V2 =0V.

The overcurrent 2 detection voltage (V_{IOV2}) is defined by the voltage between VM and VSS at which V_{DO} goes "L" from "H" when the voltage V2 is increased at the speed between 1ms and and 4ms from the normal condition V1=3.5V and V2 = 0V.

The load short-circuiting detection voltage (V_{SHORT}) is defined by the voltage between VDD and VSS at which V_{DO} goes "L" from "H" when the voltage V2 is increased at the speed between 1µs and 50µs from the normal condition V1=3.5V and V2=0V.

(4) Measurement Condition 4, Measurement Circuit 2 <Charger detection voltage, abnormal charge current detection voltage.>

Set V1=1.8V and V2=0V. Increase V1 gradually until V1=V_{DL}+(V_{HD}/2), then decrease V2 from 0V gradually. The voltage between VM and VSS when V_{DO} goes "H" from "L" is the charger detection voltage (V_{CHA}). Charger detection voltage can be measured only in the product whose overdischarge hysteresis V_{HD} \neq 0.

Set V1=3.5V and V2=0V. Decrease V2 from 0V gradually. The voltage between VM and VSS when V_{CO} goes "L" from "H" is the abnormal charge current detection voltage. The abnormal charge current detection voltage has the same value as the charger detection voltage (V_{CHA}).

(5) Measurement Condition 5, Measurement Circuit 2 <Normal operation current consumption, Power-down current consumption.>

Set V1=3.5V and V2=0V under normal condition. The current I_{DD} flowing through VDD pin is the normal operation consumption current (I_{OPE}). Set V1=V2=1.5V under overdischarge condition. The current I_{DD} flowing through VDD pin is the power-down current consumption (I_{PDN}).

(6) Measurement Condition 6, Measurement Circuit 3

< Internal resistance between VM and VDD, Internal resistance between VM and VSS. >

Set V1=1.8V and V2=0V. The resistance between VM and VDD is the internal resistance (R_{VMD}) between VM and VDD. Set V1=3.5V and V2=1.0V. The resistance between VM and VSS is the internal resistance (R_{VMS}) between VM and VSS.

(7) Measurement Condition 7, Measurement Circuit 4 <CO pin H resistance, CO pin L resistance>

Set V1=3.5V, V2=0V and V3=3.0V. CO pin resistance is the CO pin H resistance (R_{COH}). Set V1=4.5V, V2=0V and V3=0.5V. CO pin resistance is the CO pin L resistance (R_{COL}).

(8) Measurement Condition 8, Measurement Circuit 4 <DO pin H resistance, DO pin L resistance.>

Set V1=3.5V, V2=0V and V4=3.0V. DO pin resistance is the DO pin H resistance (R_{DOH}).Set V1=1.8V,V2= 0V and V4=0.5 V. DO pin resistance is the DO pin L resistance (R_{DOL}).

(9) Measurement Condition 9, Measurement Circuit 5 <Overcharge detection delay time, Overdischarge detection delay time.>

The overcharge detection delay time $(t_{\rm CU})$ is the time needed for $V_{\rm CO}$ to change from "H" to "L" just after the V1 rapid increase within 10 μs from the overcharge detection voltage $(V_{\rm CU})$ - 0.2V to the overcharge detection voltage $(V_{\rm CU})$ + 0.2V in the condition V2=0V. The overdischarge detection delay time $(t_{\rm DL})$ is the time needed for $V_{\rm DO}$ to change from "H" to "L" just after the V1 rapid decrease within 10 μs from the overdischarge detection voltage $(V_{\rm DL})$ +0.2V to the overdischarge detection voltage $(V_{\rm DL})$.

(10) Measurement Condition 10, Measurement Circuit 5 <Overcurrent 1 detection delay time, Overcurrent 2 detection delay time , Load short – circuiting detection delay time , Abnormal charge current detection delay time. >

Set V1=3.5V and V2=0V. Increase V2 from 0V to 0.35 V momentarily (within 10µs). The time needed for V_{DO} to go "L" is overcurrent 1 detection delay time (t_{IOV1}).Set V1=3.5V and V2=0V. Increase V2 from 0V to 0.7V momentarily (within 10µs). The time needed for V_{DO} to go "L" is overcurrent 2 detection delay time (t_{IOV2}).

Set V1=3.5V and V2=0V. Increase V2 from 0V to 1.6V momentarily (within 10 μ s). The time needed for V_{DO} to go "L" is the load short-circuiting detection delay time (t_{SHORT}).

Set V1=3.5V and V2=0V. Decrease V2 from 0V to 1.1V momentarily (within 10 μ s). The time needed for V_{CO} to go "L" is the abnormal charge current detection delay time. The abnormal charge current detection delay time has the same value as the overcharge detection delay time.

(11) Measurement Condition 11, Measurement Circuit 2 (Product with 0V battery charge function) <0V battery charge starting charge voltage>

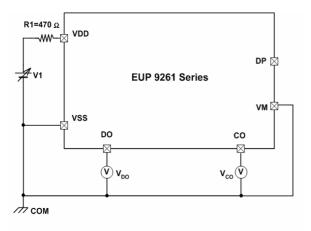
Set V1=V2=0V and decrease V2 gradually. The voltage between VDD and VM when V_{CO} goes "H" (V_{VM}+0.1V or higher) is the 0V battery charge starting charger voltage (V_{0CHA}).

(12) Measurement Condition 12, Measurement Circuit 2 (Product with 0V battery charge inhibition function) <0V battery charge inhibition battery voltage>

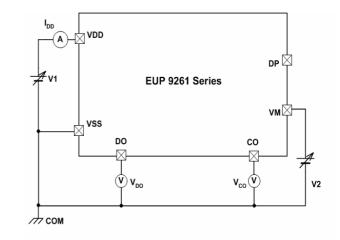
Set V1=0V and V2=4V. Increase V1 gradually. The voltage between VDD and VM when V_{CO} goes "H" (V_{VM} +0.1V or higher) is the 0V battery charge inhibition battery voltage (V_{0INH}).



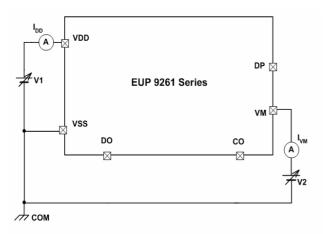
Measurement Circuit



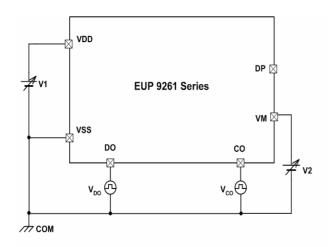
www.DataSheet4U.conMeasurement Circuit 1



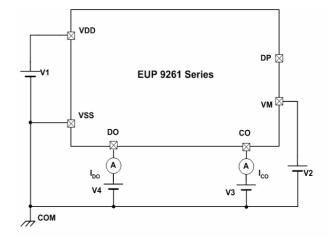
Measurement Circuit 2



Measurement Circuit 3



Measurement Circuit 5



Measurement Circuit 4



Characteristics

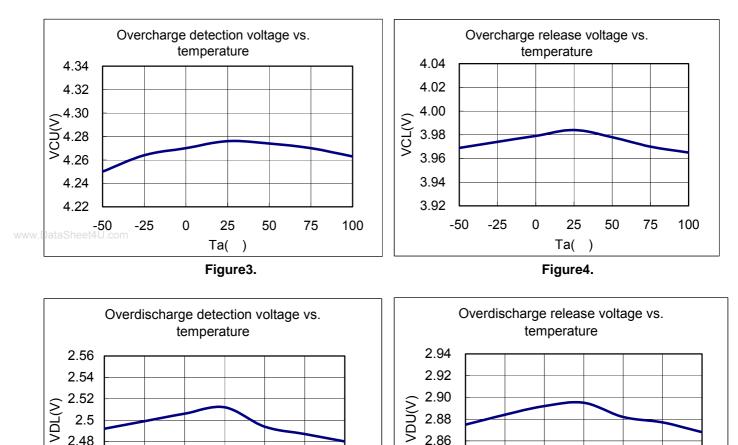
2.48 2.46

2.44

-50

-25

1. Detection/release voltage temperature characteristics



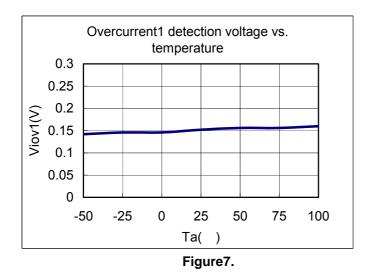
2.86

2.84

2.82

-50

-25



0

25

Figure5.

Ta() 50

75

100



Ta()

0

25

50

75

100

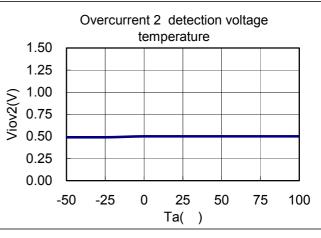
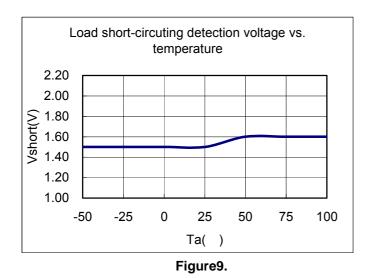
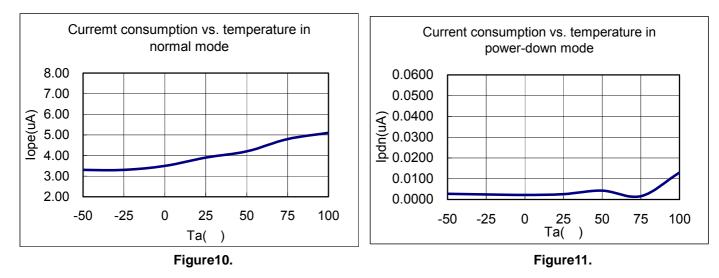


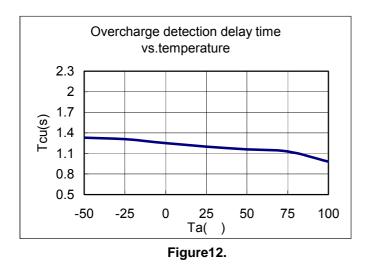
Figure8.

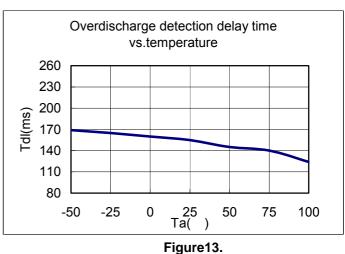


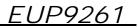
2. Current consumption temperature characteristics

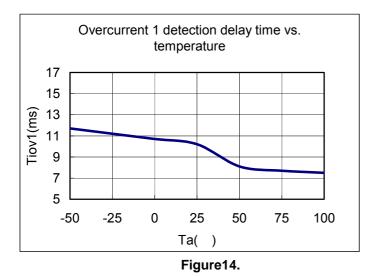


3. Detection/release delay time temperature characteristics









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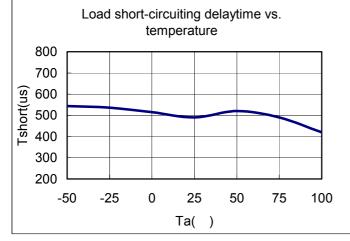


Figure16.

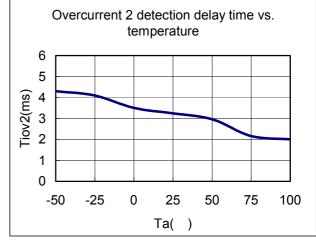


Figure15.



Description of Operation

Normal condition

The EUP9261 monitors the voltage of the battery connected between VDD and VSS pin and the voltage difference between VM and VSS pin to control charging and discharging. When the battery voltage is in the range from the overdischarge detection voltage (V_{DL}) to the overcharge detection voltage (V_{CU}), and the VM pin voltage is in the range from the overcurrent 1 detection voltage (V_{IOV1}), the IC turns both the charging and discharging control FETs on. This condition is called the normal condition, and in this condition charging and discharging can be carried out freely.

Note: When a battery is connected to the IC for the first time, the battery may not enter dischargeable state. In this case, set the VM pin voltage equal to the VSS voltage or connect a charger to enter the normal condition.

Overcurrent condition (Detection of Overcurrent 1, Overcurrent 2 and Load short-circuiting)

When the condition in which VM pin voltage is equal to or higher than the overcurrent detection voltage, condition that caused by the excess of discharging current over a specified value, continues longer than the overcharge detection delay time in a battery under the normal condition, the EUP9261 turns the discharging control FET off to stop discharging. This condition is called the overcurrent condition. Though the VM and VSS pins are shorted by the R_{VMS} resistor in the IC under the overcurrent condition, the VM pin voltage is pulled to the VDD level by the load as long as the load is connected. The VM pin voltage returns to VSS level when the load is released. The overcurrent condition returns to the normal condition when the impedance between the EB+ and EB- pin (see Figure 2) becomes higher than the automatic recoverable impedance, and the IC detects that the VM pin potential is lower than the overcurrent 1 detection voltage (V_{IOV1}).

Note: The automatic recoverable impedance changes depending on the battery voltage and overcurrent 1 detection voltage settings.

Overcharge condition

When the battery voltage becomes higher than the overcharge detection voltage (V_{CU}) during charging under the normal condition and the detection continues for the overcharge detection delay time (t_{CU}) or longer, the EUP9261 turns the charging control FET off to stop charging. This condition is called the overcharge condition. The overcharge condition is released by the following two cases ((1) and (2)):

(1) When the battery voltage falls below the overcharge release voltage, which is equal to the overcharge detection voltage (V_{CU}) overcharge detection hysteresis voltage (V_{HC}), the EUP9261 turns the charging control FET on and turns to the normal condition.

(2) When a load is connected and discharging starts, the EUP9261 turns the charging control FET on and returns to the normal condition. Just after the load is connected and discharging starts, the discharging current flows through the parasitic diode in the charging control FET. At this moment the VM pin potential becomes V_f -volt, the voltage for the parasitic diode, higher than VSS level. When the battery voltage goes under the overcharge detection voltage (V_{CU}) and provided that the VM pin voltage is higher than the overcurrent 1 detection voltage, the EUP9261 releases the overcharge condition. *Note* 1:

If the battery is charged to a voltage higher than the overcharge detection voltage (V_{CU}) and the battery voltage does not fall below the overcharge detection voltage (V_{CU}) even when a heavy load is connected, the detection of overcurrent 1, overcurrent 2 and load short-circuiting does not work. Since an actual battery has the internal impedance of several dozens of m Ω , the battery voltage drops immediately after a heavy load which causes overcurrent 1, overcurrent 2 and load short-circuiting then works.

Note2:

When a charger is connected after the overcharge detection, the overcharge condition is not released even if the battery voltage is below the overcharge release voltage (V_{CL} (= Vcu - V_{HC})). The overcharge condition is released when the VM pin voltage goes over the charger detection voltage (V_{CHA}) by removing the charger.



Overdischarge condition

When the batterv voltage falls below the overdischarge detection voltage (V_{DI}) durina discharging under the normal condition and the detection continues for the overdischarge detection delay time (t_{DI}) or longer, the EUP9261 turns the discharging control FET off to stop discharging. This condition is called the overdischarge condition. When the discharging control FET turns off, the VM pin voltage is pulled up by the R_{VMD} resistor between VM and VDD in the IC. The voltage difference between VM and VDD then falls bellow 1.3V (typ.), the current consumption is reduced to the power-down current consumption (I_{PDN}). This condition is called the power-down condition. The power-down condition is released when a charger is connected and the voltage difference between VM and VDD becomes 1.3V (typ.) or higher. Moreover when the battery voltage becomes the overdischarge detection voltage (V_{DL}) or higher, the EUP9261 turns the discharging FET on and returns to the normal condition.

Charger detection

When a battery in the overdischarge condition is connected to a charger and provided that the VM pin voltage is lower than the charger detection voltage (V_{CHA}), the EUP9261 releases the overdischarge condition and turns the discharging control FET on as the battery voltage becomes equal to or higher than the overdischarge detection voltage (V_{DL}) since the charger detection function works. This action is called charger detection. When a battery in the overdischarge condition is connected to a charger and provided that the VM pin voltage is not lower than the charger detection voltage (V_{CHA}), the EUP9261 releases the Overdischarge condition when the battery voltage reaches the overdischarge detection voltage (V_{CHA}), the EUP9261 releases the Overdischarge condition when the battery voltage reaches the overdischarge detection voltage (V_{DL}) overdischarge hysteresis (V_{HD}) or higher.

Abnormal charge current detection

If the VM pin voltage falls below the charger detection voltage (V_{CHA}) during charging under normal condition and it continues for the overcharge detection delay time (t_{CU}) or longer, the charging control. FET turns off and charging stops. This action is called the abnormal charge current detection. Abnormal charge current detection works when the DO pin voltage is "H" and the VM pin voltage falls below the charger detection voltage (V_{CHA}). Consequently, if an abnormal charge current flows to an over-discharged battery, the EUP9261 turns the charging control FET off and stops charging after the battery voltage becomes higher than the overdischarge detection voltage "H", and still after the overcharge detection delay time (t_{CU}) elapses.

Abnormal charge current detection is released when the voltage difference between VM pin and VSS pin becomes less than charger detection voltage (V_{CHA}).

Delay circuits

The detection delay times are generated by dividing the approximate 3.5 KHz clock with a counter.

Note1:

Note2

The detection delay time for overcurrent 2 and load short-circuiting start when the overcurrent 1 is detected. As soon as the overcurrent 2 or load short-circuiting is detected over the detection delay time for overcurrent 2 or load short-circuiting after the detection of Overcurrent 1, the EUP9261 turns the discharging control FET off.

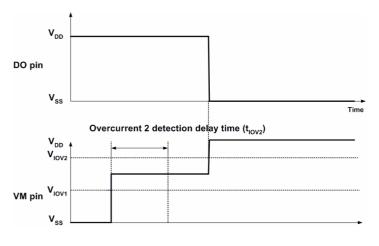


Figure17.

When the overcurrent is detected and it continues for longer than the Overdischarge detection delay time without releasing the load, the load, the condition changes to the power-down condition when the battery voltage falls below the Overdischarge detection voltage. *Note3:*

When the falls battery voltage below the Overdischarge detection voltage due to the overcurrent, the EUP9261 turns the discharging control FET off by the overcurrent detection. And in this case the recovery of the battery voltage is so slow that the battery voltage after the Overdischarge detection delay time is still lower than the Overdischarge detection voltage, the EUP9261 transits to the power-down condition.



FUP9261

DP pin

The DP pin is a test pin for delay time measurement and for output delay time reduction or bypass. It should be open or VDD level in the actual application.

For reducing delay time, connect this pin with a $300k\Omega$ resistor to VSS. An internal clock can be measured. Under this condition, output delay time of over-charge, over-discharge, over-current1 and over-current2 can be shorter than the setting value (delay time for over charge becomes about 1/64 of normal state).

By forcing this pin to VSS, output delay time circuit can be disabled.

0V battery charge function^{*1*2}

This function is used to recharge the connected battery whose voltage is 0V due to the self-discharge.

When the OV battery charge starting charge voltage (VOCHA) or higher is applied between EB+ pin and EB-pin by connecting a charger, the charging control FET gate is fixed to VDD pin voltage. When the voltage between the gate and source of the charging control FET becomes equal to or higher than the turn-on voltage e by the charger voltage, the charging control FET turns on to start charging. At this time, the discharging control FET is off and the charging current flows through the internal parasitic diode in the discharging control FET. When the battery voltage becomes equal to or higher than the overdischarge release voltage (VDU), the EUP9261 enters the normal condition.

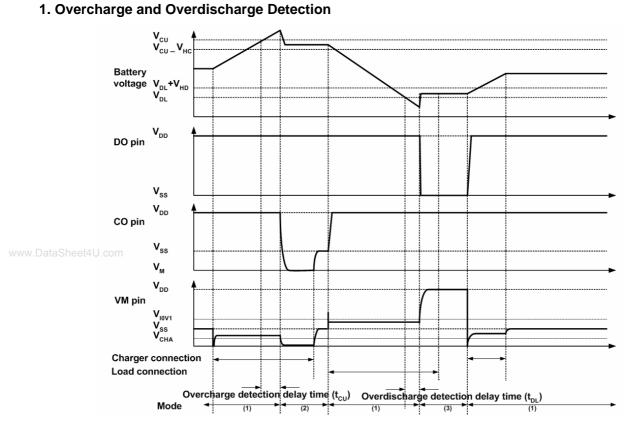
0V battery charge inhibition function^{*1}

This function inhibits the recharging when a battery which is short-circuited (0V) internally is connected. When the battery voltage is 0.6V (typ.) or lower, the charging control FET gate is fixed to EB- pin voltage to inhibit charging. When the battery voltage is the 0V battery charge inhibition battery voltage (V0INH) or higher, charging can be performed.

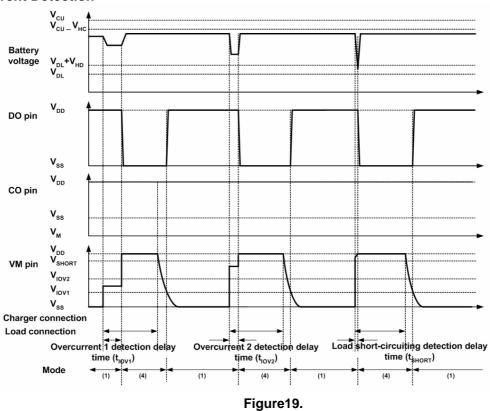
- *1.Some battery providers do not recommend charging for completely self-discharged battery. Please ask battery providers before determining the 0V battery charge function.
- *2. The 0V battery charge function has higher priority than the abnormal charge current detection function. Consequently, a product with the 0V battery charge function charges a battery forcedly and abnormal charge current cannot be detected when the battery voltage is low.



Operation Timing Chart





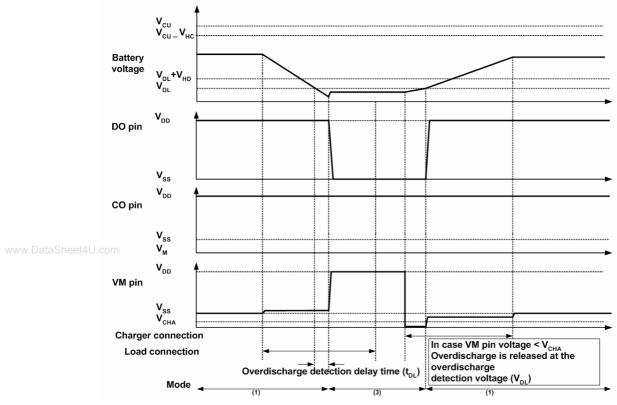


Note: (1) Normal condition. (2) Overcharge condition. (3) Overdischarge condition. (4) Overcurrent condition The charger is supposed to charge with constant current



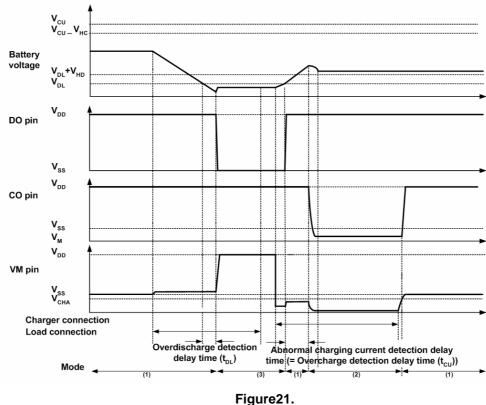
2. Overcurrent Detection

3. Charger Detection







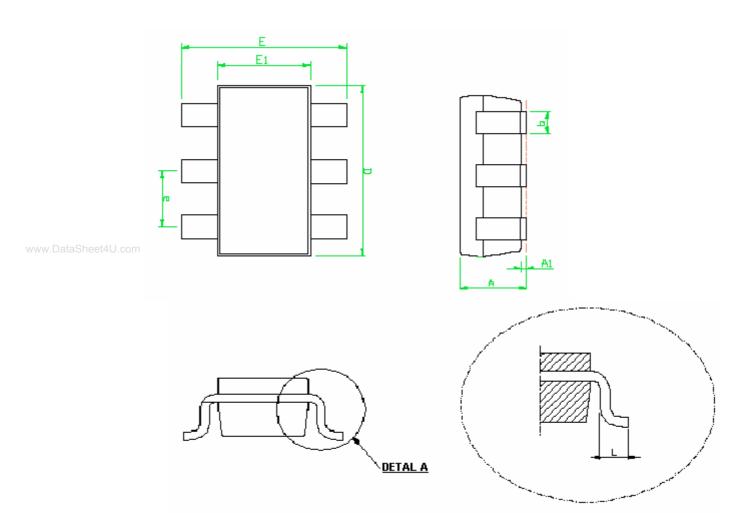


Note: (1) Normal condition. (2) Overcharge condition. (3) Overdischarge condition. (4) Overcurrent condition The charger is supposed to charge with constant current



Package Information

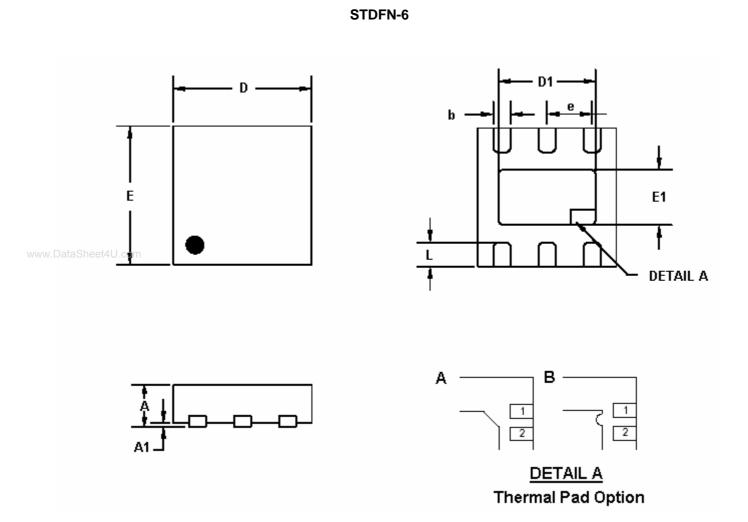




ETAL A

SYMBOLS	MILLIMETERS		INCHES	
ST MIDULS	MIN.	MAX.	MIN.	MAX.
А	-	1.45	-	0.057
A1	0.00	0.15	0.000	0.006
b	0.30	0.50	0.012	0.020
D	2.90		0.114	
E1	1.60		0.00	53
e	0.95		0.03	37
Е	2.60	3.00	0.102	0.118
L	0.30	0.60	0.012	0.024

Package Information



SYMBOLS	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
А	0.50	0.60	0.020	0.024	
A1	0.00	0.05	0.000	0.002	
b	0.15	0.35	0.006	0.014	
D	1.85	2.15	0.073	0.085	
D1	1.40		0.055		
Е	1.85	2.15	0.073	0.085	
E1	0.80		0.031		
e	0.65		e 0.65 0.026		26
L	0.25	0.45	0.010	0.018	